



Buffered Power Half Bridge

General Description

The AAT4900 FastSwitch is a member of Skyworks' Application Specific Power MOSFET (ASPM[™]) product family. It is a buffered power half-bridge, consisting of low on resistance power MOSFETs with integrated control logic. This device operates with inputs ranging from 2.0V to 5.5V, making it ideal for 2.5V, 3V, and 5V systems. The device is protected from shoot-through current with its own control circuitry. The AAT4900 is capable of very fast switching times and is ideal for use in high frequency DC/DC converters. The quiescent supply current is a low 4mA at 1MHz CLK frequency. In shutdown mode, the supply current decreases to less than 1µA max.

The AAT4900 is available in a Pb-free 5-pin SOT23 or 8-pin SC70JW package and is specified over the -40°C to +85°C temperature range.

Features

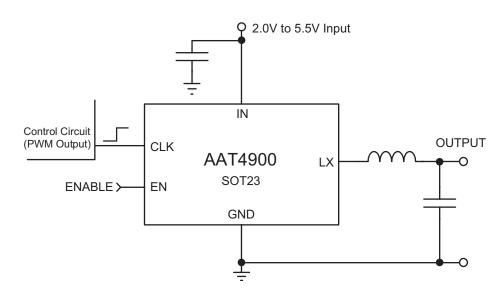
- 2.0V to 5.5V Input Voltage Range
- 105m Ω (typ) Low Side Switch R_{DS(ON)}
- 130mΩ (typ) High Side Switch R_{DS(ON)}
- Low Quiescent Current:
 - 1µA (max) DC
 - 4mA at 1MHz
- Only 2.5V Needed for Control Signal Input
- Break-Before-Make Shoot-Through Protection
- Temperature Range: -40°C to +85°C
- 5-Pin SOT23 or 8-Pin SC70JW Package

Applications

- DC Motor Drive
- High Frequency DC/DC Converters
- MOSFET Driver

Typical Application

DC/DC Converter Output Stage



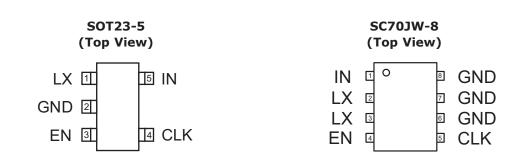


Buffered Power Half Bridge

Pin Descriptions

Pi	n #		
SOT23-5	SC70JW-8	Symbol	Function
1	2, 3	LX	Inductor connection. LX output is controlled by CLK and EN (see Control Logic Table).
2	6, 7, 8	GND	Ground connection.
3	4	EN	Active-high enable input. A logic low signal puts the LX output pin in high impedance mode.
4	5	CLK	Logic input signal determines the state of LX output.
5	1	IN	Supply voltage input. Input voltage range from 2.0V to 5.5V.

Pin Configuration





Buffered Power Half Bridge

Control Logic Table

Inpu	its	Output	
CLK	EN	LX	
0	0	High Impedance	
0	1	V _{IN}	
1	0	High Impedance	
1	1	Ground	

Absolute Maximum Ratings¹

 $T_A = 25^{\circ}C$, unless otherwise noted.

Symbol	Description	Value	Units
V _{IN}	IN to GND	-0.3 to 6	V
V _{EN} , V _{CLK}	EN, CLK to GND	-0.3 to 6	V
V _{OUT}	OUT to GND	-0.3 to V _{IN} +0.3	V
I _{MAX}	Maximum Continuous Switch Current	2	A
T ₁	Operating Junction Temperature Range	-40 to 150	°C
V _{ESD}	ESD Rating ² - HBM	4000	V
T _{LEAD}	Maximum Soldering Temperature (at Leads)	300	°C

Thermal Information³

Symbol	Description	Value	Units
Θ_{JA}	Thermal Resistance (SOT23-5, SC70JW-8)	190	°C/W
PD	Power Dissipation (SOT23-5, SC70JW-8)	526	mW

^{1.} Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional operation at conditions other than the operating conditions specified is not implied. Only one Absolute Maximum Rating should be applied at any one time.

^{2.} Human body model is a 100pF capacitor discharged through a $1.5k\Omega$ resistor into each pin.

^{3.} Mounted on a demo board.



Buffered Power Half Bridge

Electrical Characteristics

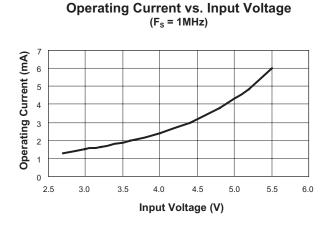
$V_{\rm IN}$ = 5V, T_{A} = -40°C to +85°C, unless otherwise noted. Typical values are at T_{A} = 25°C.

Symbol	Description	Conditions	Min	Тур	Max	Units
V _{IN}	Operation Voltage		2.0		5.5	V
I _{QAC}	AC Quiescent Current	IN = 5V, EN = IN, CLK = 1MHz, $I_{LX} = 0$		4	9	mA
I _{QDC}	DC Quiescent Current	IN = 5V, EN = IN, CLK = GND, $I_{LX} = 0$			1	μA
I _{Q(OFF)}	Off-Supply Current	EN = CLK = GND, IN = LX = 5.5V			1	μA
$I_{SD(OFF)}$	Off-Switch Current	$EN = GND$, $IN = 5.5V$, $V_{OUT} = 0$ or $LX = IN$		0.03	1	μA
		$IN = 5V, T_A = 25^{\circ}C$		130	165	mΩ
R _{DS(ON)H}	High Side MOSFET On Resistance	$IN = 3V, T_A = 25^{\circ}C$		165	195	
		$IN = 2V, T_A = 25^{\circ}C$		235		
		$IN = 5V, T_A = 25^{\circ}C$		105	145	
R _{DS(ON)L}	Low Side MOSFET On Resistance	$IN = 3V, T_A = 25^{\circ}C$		135 175 m	mΩ	
		$IN = 2V, T_A = 25^{\circ}C$		200		
V _{ONL}	CLK, EN Input Low Voltage	EN Input Low Voltage IN = 2V to 5.5V			0.4	V
V _{ONH}	CLK, EN Input High Voltage	IN = 2V to 5.5V	1.5			V
I _{SINK}	CLK, EN Input Leakage	CLK, EN = 5.5V		0.01	1	μA
т	Break-Before-Make Time	CLK Rising		5		
Т _{ввм}	Dreak-Delore-Make Tille	CLK Falling		5		ns
т		CLK Rising		30		nc
T _{ON-DLY}	CLK to LX Delay	CLK Falling		40		ns
т	EN to OUT HIZ Dolov	CLK = GND		40		
T_{HIZ}	EN to OUT HiZ Delay	CLK = IN		40		ns

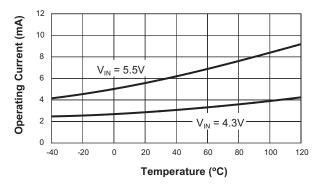


Buffered Power Half Bridge

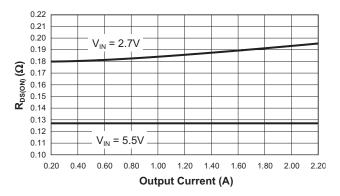
Typical Characteristics



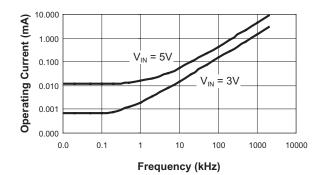
Operating Current vs. Temperature (F_s = 1MHz)



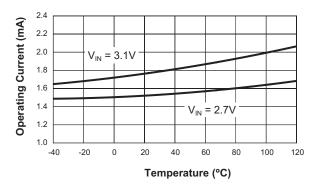
High Side R_{DS(ON)} vs. Output Current



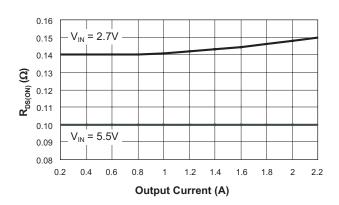
Operating Current vs. Switching Frequency



Operating Current vs. Temperature (F_s = 1MHz)



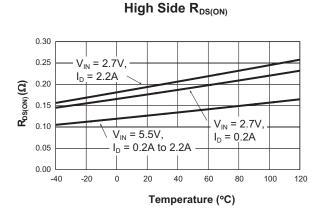
Low Side R_{DS(ON)} vs. Output Current

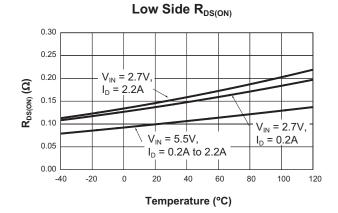




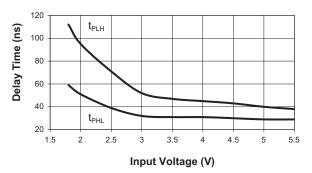
Buffered Power Half Bridge

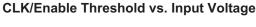
Typical Characteristics

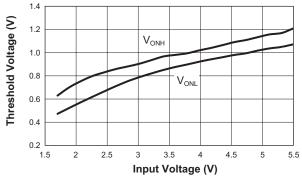




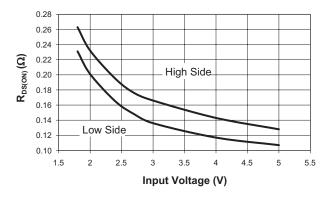
Propagation Delay vs. Input Voltage (C_L = 1000pF)







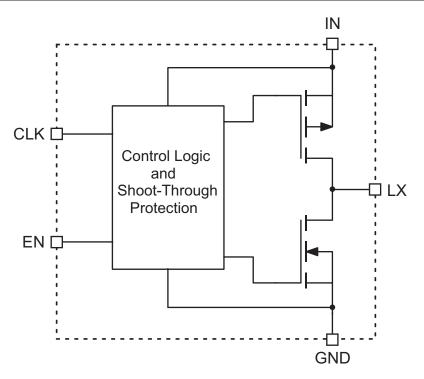
R_{DS(ON)} vs. Input Voltage





Buffered Power Half Bridge

Functional Block Diagram



Typical Applications

DC/DC Converter

The most common AAT4900 applications include a DC/ DC converter output power stage and a MOSFET gate drive buffer.

Figure 1 shows a common configuration when used as a DC/DC converter power stage with synchronous rectification. The enable pin can be used to force the LX output to a high impedance state under light load conditions. This enables the output inductor to operate in discontinuous conduction mode (DCM), improving efficiency under light load conditions. The body diode associated with the low side switching device gives the AAT4900 inductive switching capability, clamping the LX node at a diode drop below GND during the break-before-make time.

Synchronous Buck DC/DC Converter Application

The losses associated with the AAT4900 high side switching MOSFET are due to switching losses and conduction losses. The conduction losses are associated with the $R_{DS(ON)}$ characteristics of the output switching device. At the full load condition, assuming continuous conduction mode (CCM), the on losses can be derived from the following equations.

Eq. 1: D =
$$\frac{V_0}{V_{IN}}$$

D is the duty cycle.

Eq. 2:
$$\Delta I = \frac{V_O}{L \cdot F_S} \left(1 - \frac{V_O}{V_{IN}} \right)$$

 ΔI is the *peak-to-peak* inductor ripple current.



Buffered Power Half Bridge

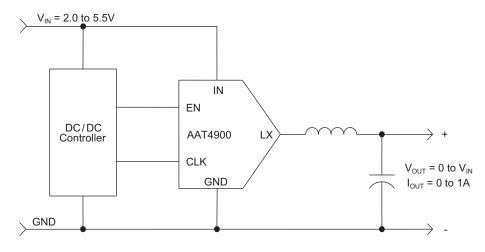


Figure 1: AAT4900 DC/DC Converter Power Stage.

High Side Switch RMS Current

Eq. 3:
$$I_{\text{RMS(HS)}} = \sqrt{\left(I_0^2 + \frac{\Delta I^2}{12}\right) \cdot D}$$

Low Side Switch RMS Current

The low side RMS current is estimated by the following equation.

Eq. 4:
$$I_{\text{RMS}(\text{LS})} = \sqrt{\left(I_0^2 + \frac{\Delta I^2}{12}\right) \cdot (1 - D)}$$

Total Losses

A simplified form of the above results (where the above descriptions of $I_{\mbox{\tiny RMS}}$ has been approximated with $I_{\mbox{\tiny o}})$ is given by:

Eq. 5:
$$P_{LOSS} = \frac{I_{O}^{2} \cdot (R_{DS(ON)H} \cdot V_{O} + R_{DS(ON)L} \cdot (V_{IN} - V_{O}))}{V_{IN}}$$

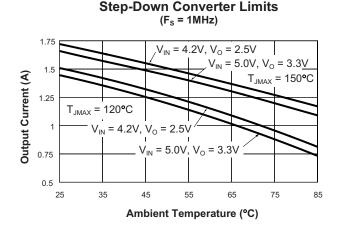
+ $(t_{sw} \cdot F_{S} \cdot I_{O} + I_{Q}) \cdot V_{IN}$

Substitution of the I_{RMS} equations with I_{O} results in very little error when the inductor ripple current is 20% to 40% of the full load current. The equation also includes switching and quiescent current losses where t_{SW} is approximated at 18 nsec and I_{Q} is the no load quiescent current of the AAT4900. Quiescent current losses are associated with the gate drive of the output stage and biasing. Since the gate drive current varies with fre-

quency and voltage, the bias current must be checked at the frequency, voltage, and temperature of operation with no load attached to the LX node. Once the above losses have been determined, the maximum junction temperature can be calculated.

Eq. 6: $T_{J(MAX)} = P_{LOSS} \cdot \Theta_{JC} = T_{AMB}$

Using the above equations, the graph below shows the current capability for some typical applications with maximum junction temperatures of 150°C and 120°C. The increase in $R_{\text{DS(ON)}}$ vs. temperature is estimated at $3.75 m\Omega$ for a 10°C increase in junction temperature.





Buffered Power Half Bridge

Gate Drive

When used as a MOSFET gate driver, the break-beforemake shoot-through protection significantly reduces losses associated with the driver at high frequencies. (See Figure 2.)

The low $R_{DS(ON)}$ of the output stage allows for a high peak gate current and fast switching speeds. A small package size facilitates close placement to the power device for optimum switching performance. The logic level inputs (CLK and EN) are high impedance inputs.

Gate Drive Current Ratings

An estimate of the maximum gate drive capability with no external series resistor can be derived from Equation 7. Note that the quiescent current varies with the ambient temperature, frequency of operation, and input voltage. The graphs below display the quiescent current and maximum gate charge drive capability at 85°C ambient vs. frequency for various input voltages.

Eq. 7:
$$Q_{G(MAX)} = \frac{1}{F_S} \cdot \left(\frac{T_{J(MAX)} - T_{AMB}}{\theta_{JA} \cdot V_{IN(MAX)}} - I_Q \right)$$

= $\frac{1}{1MHz} \cdot \left(\frac{120^{\circ}C - 85^{\circ}C}{190^{\circ}C/W \cdot 4.2V} - 3.2mA \right)$
= 40nC

The quiescent current was first measured over temperature for various input voltages with no load attached. Equation 7 was then used to derive the maximum gate charge capability for the desired maximum junction temperature. Q_G is the gate charge required to raise the gate of the load MOSFET to the input voltage. This value is taken from the MOSFET manufacturer's gate charge curve.

$\mathbf{Frequency (kHz)}^{100}$

No Load Operating Current at 85°C Ambient



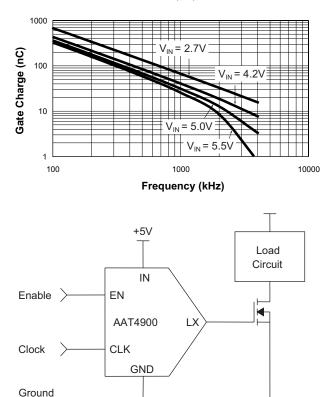


Figure 2: AAT4900 Gate Drive Configuration.

AAT4900

Buffered Power Half Bridge

Motor Drive

The AAT4900 is also ideally suited for use as an efficient output driver for DC brushless motor control. The inductive load switching capability of the AAT4900 eliminates the need for external diodes. A typical motor control circuit is illustrated in Figure 3.

Recommended Decoupling Layout Pattern

Because of the extremely fast switching speed and the high switching currents, optimum placement of the input capacitor is critical. It is recommended that a 0.1μ F to 10μ F 0805 or 1206 ceramic capacitor be placed as close as possible to the IC, as shown in Figure 4. This helps to decouple the switching transients from the stray inductance present in the PC board.

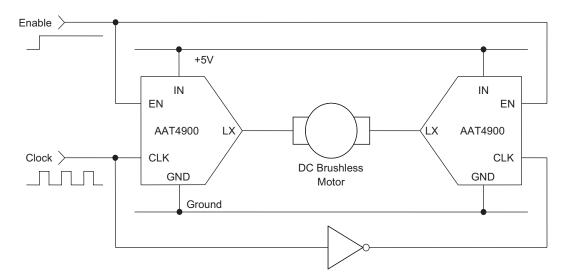


Figure 3: Typical Motor Control Block Diagram.

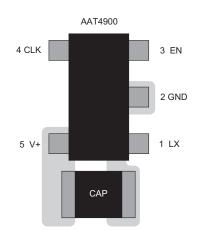
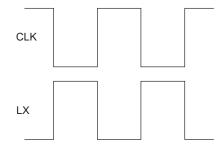


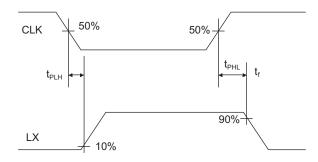
Figure 4: Recommended Decoupling Layout Pattern.

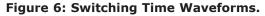


Buffered Power Half Bridge









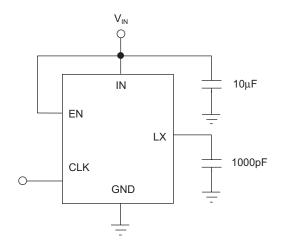


Figure 7: Propagation Delay Test Circuit.



Buffered Power Half Bridge

Ordering Information

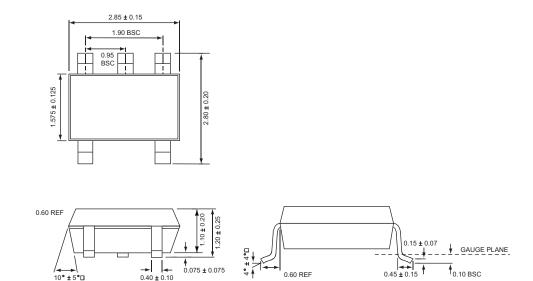
Part Number (Tape and Reel) ²	Marking ¹	Package
AAT4900IGV-T1	ABXYY	SOT23-5
AAT4900IJS-T1	ABXYY	SC70JW-8



Skyworks GreenTM products are compliant with all applicable legislation and are halogen-free. For additional information, refer to *Skyworks Definition of Green*TM, document number SQ04-0074.

Package Information





All dimensions in millimeters.

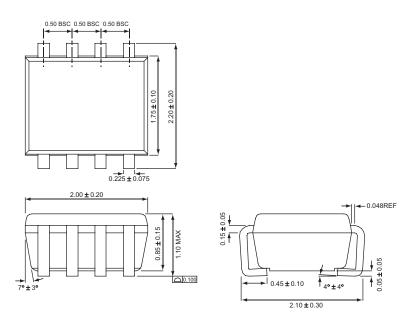
1. XYY = assembly and date code.

2. Sample stock is generally held on part numbers listed in BOLD.



Buffered Power Half Bridge

SC70JW-8



All dimensions in millimeters.

Copyright © 2012 Skyworks Solutions, Inc. All Rights Reserved.

Information in this document is provided in connection with Skyworks Solutions, Inc. ("Skyworks") products or services. These materials, including the information contained herein, are provided by Skyworks as a service to its customers and may be used for informational purposes only by the customer. Skyworks assumes no responsibility for errors or omissions in these materials or the information contained herein. Skyworks may change its documentation, products, services, specifications or product descriptions at any time, without notice. Skyworks makes no commitment to update the materials or information and shall have no responsibility whatsoever for conflicts, incompatibilities, or other difficulties arising from any future changes.

No license, whether express, implied, by estoppel or otherwise, is granted to any intellectual property rights by this document. Skyworks assumes no liability for any materials, products or information provided hereunder, including the sale, distribution, reproduction or use of Skyworks products, information or materials, except as may be provided in Skyworks Terms and Conditions of Sale.

THE MATERIALS, PRODUCTS AND INFORMATION ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, WHETHER EXPRESS, IMPLIED, STATUTORY, OR OTHERWISE, INCLUDING FITNESS FOR A PARTICULAR PURPOSE OR USE, MERCHANTABILITY, PERFORMANCE, QUALITY OR NON-INFRINGEMENT OF ANY INTELLECTUAL PROPERTY RIGHT; ALL SUCH WARRANTIES ARE HEREBY EXPRESSLY DISCLAIMED. SKYWORKS DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. SKYWORKS SHALL NOT BE LIABLE FOR ANY DAMAGES, IN-CLUDING BUT NOT LIMITED TO ANY SPECIAL, INDIRECT, INCIDENTAL, STATUTORY, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS THAT MAY RESULT FROM THE USE OF THE MATERIALS OR INFORMATION, WHETHER OR NOT THE RECIPIENT OF MATERIALS HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGE.

Skyworks products are not intended for use in medical, lifesaving or life-sustaining applications, or other equipment in which the failure of the Skyworks products could lead to personal injury, death, physical or environmental damage. Skyworks customers using or selling Skyworks products for use in such applications do so at their own risk and agree to fully indemnify Skyworks for any damages resulting from such improper use or sale.

Customers are responsible for their products and applications using Skyworks products, which may deviate from published specifications as a result of design defects, errors, or operation of products outside of published parameters or design specifications. Customers should include design and operating safeguards to minimize these and other risks. Skyworks assumes no liability for applications assistance, customer product design, or damage to any equipment resulting from the use of Skyworks products outside of stated published specifications or parameters.

Skyworks, the Skyworks symbol, and "Breakthrough Simplicity" are trademarks or registered trademarks of Skyworks Solutions, Inc., in the United States and other countries. Third-party brands and names are for identification purposes only, and are the property of their respective owners. Additional information, including relevant terms and conditions, posted at www.skyworksinc.com, are incorporated by reference.



Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

- > Sales :
 - Direct +86 (21) 6401-6692
 - Email amall@ameya360.com
 - QQ 800077892
 - Skype ameyasales1 ameyasales2

> Customer Service :

Email service@ameya360.com

> Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com